EW-412, EW-512

BIPOLAR HALL EFFECT LATCHES

Note: It is requested to read and accept "IMPORTANT NOTICE" written on the back of the front cover of this catalogue

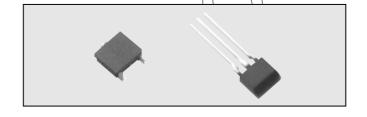
ASAHI HALL EFFECT ICs

ASAHI KASEI ELECTRONICS Hall Effect ICs are composed of a Ultla-high sensitive InSb Hall element and a signal processing IC chip in a package. ASAHI KASEI ELECTRONICS Hall Effect ICs have high sensitivity and good stability.

FEATURES

High Sensitivity (Bop:1mT to 6mT)
4.5V to 18V Operation
Highly Resistant to Mechanical Stress
Stable Operation in Broad Temperature Range
Compact Size

With Load Resistance



APPLICATIONS

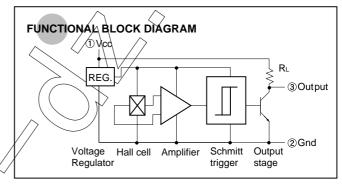
Rotor Position Sensor for Precision Motors.

Stroke Sensor

Proximity Switch

Encorder

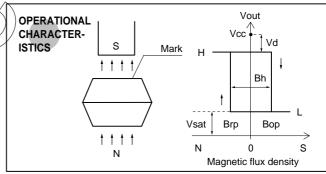
Current Switch etc



ABSOLUTE MAXIMUM RATINGS(Ta = 25)

Item	Symbol	Limit	Unit
Supply Voltage * 1	Vcc	18	\ \ \ \
Output "ON" Current	I sink	15	mA
Operating Temperature Range	Topr	- 30~ + 115	
Storage Temperature Range	Tstg	- 40 ~ + 125	

^{*1:}Please refer to(Fig 1) DERATING CURVE



ELECTRICAL CHARACTERISTICS(Ta = 25 , Vcc = 4.5 ~ 18V DC.)

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Operate Point	Bop	Vcc=12V	1		6	mT	
Release Point	Bip	Vcc=12V	- 6		- 1	mT	
Hysteresis	Bh		2			mT	
Output Saturation Voltage	Vsat	Output"L", Vcc=12V			0.4	V	
Supply Current	I cc	Output"H", Vcc=12V			8	mA	
Internal Load Resistance	R∟		7		13	К	
Output Down Voltage	Vd				20	mV	

1mT = 10Gauss

Please be aware that AKE products are not intended for use in life support appliances, devices, or systems. Use of AKE products in such applications requires the written approval of the appropriate AKE officer. Certain applications using semiconductor devices may involve potential risks of personal risky, property damage, or loss of life. In order to minimize these risks, adequate design and operating safeguards should be provided by the customer to minimize themselves the risk of the customer using AKE devices or systems.

